

Three-Wire Serial EEPROM 1-Kbit (128 x 8 or 64 x 16)

Features

- Low-Voltage Operation:
 - V_{CC} = 1.8V to 5.5V
- User-Selectable Internally Organized as 128 x 8 (1K) or 64 x 16 (1K)
- Non-Selectable Internal Organization as 64 x 16 (1K), AT93C46E Only
- Industrial Temperature Range: -40°C to +85°C
- Three-Wire Serial Interface
- 2 MHz Clock Rate (5V)
- Self-Timed Write Cycle within 5 ms Maximum
- High Reliability:
 - Endurance: 1,000,000 write cycles
 - Data retention: 100 years
- Green Package Options (Lead-free/Halide-free/RoHS compliant)
- Die Sale Options: Wafer Form and Tape and Reel

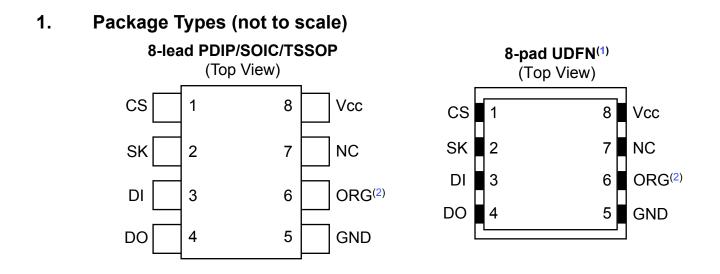
Packages

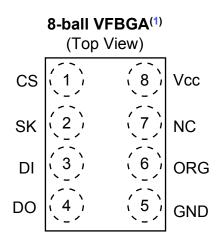
• 8-Lead PDIP, 8-Lead SOIC, 8-Lead TSSOP, 8-Pad UDFN and 8-Ball VFBGA

Table of Contents

Fea	tures		1			
Pac	kages.		1			
1.	Packa	age Types (not to scale)	4			
2.	Pin De	escriptions	5			
	2.1.	Chip Select (CS)	5			
	2.2.	Serial Data Clock (SK)				
	2.3.	Serial Data Input (DI)				
	2.4.	Serial Data Output (DO)				
	2.5.	Ground (GND)				
	2.6.	Internal Organization (ORG)				
	2.7.	Device Power Supply (V _{CC})	6			
3.	Descr	iption	7			
	3.1.	Block Diagram	7			
4.	Electr	ical Characteristics	8			
	4.1.	Absolute Maximum Ratings	8			
	4.2.	DC and AC Operating Range				
	4.3.	DC Characteristics				
	4.4.	AC Characteristics				
	4.5.	Synchronous Data Timing	10			
	4.6.	Electrical Specifications.				
5.	Devic	e Commands and Addressing	13			
	5.1.	Read Operation (READ)	.13			
	5.2.	Erase/Write Enable (EWEN)	14			
	5.3.	Erase/Write Disable (EWDS)	14			
	5.4.	Erase Operation (ERASE)	.15			
	5.5.	Write Operation (WRITE)	15			
	5.6.	Write All (WRAL)	16			
	5.7.	Erase All (ERAL)	16			
6.	Packa	iging Information	18			
	6.1.	Package Marking Information	.18			
7.	7. Revision History					
The	Micro	chip Website	32			
	Product Change Notification Service					
Customer Support						
Pro	duct Id	entification System	.33			
Mic	Microchip Devices Code Protection Feature					

Legal Notice	34
Trademarks	34
Quality Management System	35
Worldwide Sales and Service	.36





Note:

- 1. This package is only available on the AT93C46D.
- 2. ORG pin is No Connect (NC) on the AT93C46E device.

2. Pin Descriptions

The descriptions of the pins are listed in Table 2-1.

Table 2-1. Pin Function Table

Name	8-Lead PDIP	8-Lead SOIC	8-Lead TSSOP	8-Pad UDFN(<u>1</u>)	8-Ball VFBGA	Function
CS	1	1	1	1	1	Chip Select
SK	2	2	2	2	2	Serial Data Clock
DI	3	3	3	3	3	Serial Data Input
DO	4	4	4	4	4	Serial Data Output
GND	5	5	5	5	5	Ground
ORG ⁽²⁾	6	6	6	6	6	Internal Organization
NC	7	7	7	7	7	No Connect
VCC	8	8	8	8	8	Device Power Supply

Note:

- 1. The exposed pad on this package can be connected to GND or left floating.
- 2. The Internal Organization (ORG) pin is a No Connect (NC) on the AT93C46E device.

2.1 Chip Select (CS)

The Chip Select (CS) pin is used to control device selection. The AT93C46D/AT93C46E is selected when the CS pin is high. When the device is not selected, data will not be accepted via the Serial Data Input (DI) pin, and the Serial Output (DO) pin will remain in a high-impedance state.

2.2 Serial Data Clock (SK)

The Serial Data Clock (SK) pin is used to synchronize the communication between a master and the AT93C46D/ AT93C46E. Instructions, addresses or data present on the Serial Data Input (DI) pin is latched in on the rising edge of SK, while output on the Serial Data Output (DO) pin is also clocked out on the rising edge of SK.

2.3 Serial Data Input (DI)

The Serial Data Input (DI) pin is used to transfer data into the device. It receives instructions, addresses and data. Data is latched on the rising edge of the Serial Data Clock (SK).

2.4 Serial Data Output (DO)

The Serial Data Output (DO) pin is used to transfer data out of the AT93C46D/AT93C46E. During a read sequence, data is shifted out on this pin after the rising edge of the Serial Data Clock (SK).

This pin also outputs the Ready/Busy status of the part if CS is brought high after being low for a minimum of t_{cs} and an erase or write operation has been initiated.

2.5 Ground (GND)

The ground reference for the power supply. The Ground (GND) pin should be connected to the system ground.

2.6 Internal Organization (ORG)

The Internal Organization (ORG) pin is used to select between the x16 or x8 memory organizations of the device. When the ORG pin is tied to V_{CC} , the x16 memory organization is selected. When the ORG pin is tied to GND, the x8 memory organization is selected.

If the ORG pin is left unconnected and the application does not load the input beyond the capability of the internal 1 $M\Omega$ pull-up resistor, then the x16 organization is selected.

Note: This pin is a No Connect (NC) on the AT93C46E.

2.7 Device Power Supply (V_{CC})

The Device Power Supply (V_{CC}) pin is used to supply the source voltage to the device. Operations at invalid V_{CC} voltages may produce spurious results and should not be attempted.

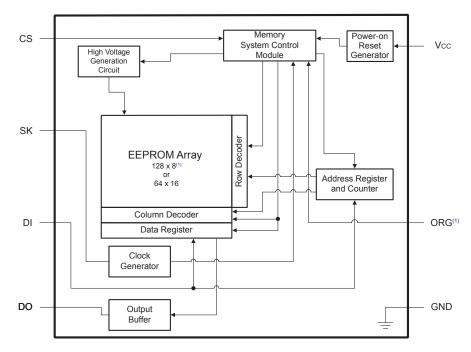
3. Description

The AT93C46D provides 1,024 bits of Serial Electrically Erasable and Programmable Read-Only Memory (EEPROM) organized as 64 words of 16 bits each (when the ORG pin is connected to V_{CC}) and 128 words of 8 bits each (when the ORG pin is tied to ground). The device is optimized for use in many industrial and commercial applications where low-power and low-voltage operations are essential. The AT93C46D is available in space-saving 8-lead PDIP, 8-lead SOIC, 8-lead TSSOP, 8-pad UDFN and 8-ball VFBGA packages. All packages operate from 1.8V to 5.5V.

The AT93C46E provides 1,024 bits of Serial Electrically Erasable and Programmable Read-Only Memory (EEPROM) organized as 64 words of 16 bits each only. The AT93C46E does not offer the ORG pin so organization is not user-selectable on this device. The device is optimized for use in many industrial and commercial applications where low-power and low-voltage operations are essential. The AT93C46E is also available in space-saving and 8-lead PDIP, 8-lead SOIC and 8-lead TSSOP packages. All packages operate from 1.8V to 5.5V.

The AT93C46D/AT93C46E is enabled through the Chip Select (CS) pin and accessed via a three-wire serial interface consisting of Data Input (DI), Data Output (DO), and Serial Data Clock (SK). Upon receiving a READ instruction at DI, the address is decoded, and the data is clocked out serially on the DO pin. The write cycle is completely self-timed, and no separate erase cycle is required before write. The write cycle is only enabled when the part is in the Erase/ Write Enable state. When CS is brought high following the initiation of a write cycle, the DO pin outputs the Ready/ Busy status of the part.

3.1 Block Diagram



Note:

1. The organization of the AT93C46E is not selectable by the ORG pin and defaults to 64x16. If the x16 organization is the mode of choice and pin 6 (ORG) is left unconnected, Microchip recommends using AT93C46E device.

4. Electrical Characteristics

4.1 Absolute Maximum Ratings

Temperature under bias	-55°C to +125°C
Storage temperature	-65°C to +150°C
V _{cc}	6.25V
Voltage on any pin with respect to ground	-1.0V to +7.0V
DC output current	5.0 mA
ESD protection	2 kV

Note: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operation listings of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

4.2 DC and AC Operating Range

Table 4-1. DC and AC Operating Range

AT93C46D/AT93C46E		
Operating Temperature (Case)	Industrial Temperature Range	-40°C to +85°C
V _{CC} Power Supply	Low-Voltage Grade	1.8V to 5.5V

4.3 DC Characteristics

Table 4-2. DC Characteristics⁽¹⁾

Parameter	Symbol	Minimum	Typical	Maximum	Units	Test Conditions
Supply Voltage	V _{CC1}	1.8	—	5.5	V	
Supply Voltage	V _{CC2}	2.7	—	5.5	V	
Supply Voltage	V _{CC3}	4.5	—	5.5	V	
Supply Current	I _{CC1}		0.5	2.0	mA	V _{CC} = 5.0V, Read at 1 MHz
Supply Current	I _{CC2}		0.5	2.0	mA	V _{CC} = 5.0V, Write at 1 MHz
Standby Current (1.8V Option)	I _{SB1}		0.4	1.0	μΑ	V _{CC} = 1.8V, CS = 0V
Standby Current (2.7V Option)	I _{SB2}		6.0	10.0	μΑ	V _{CC} = 2.7V, CS = 0V
Standby Current (5.0V Option)	I _{SB3}		10.0	15.0	μΑ	V _{CC} = 5.0V, CS = 0V
Input Leakage Current	IIL		0.1	1.0	μΑ	$V_{IN} = 0$ to V_{CC}
Output Leakage Current	I _{LO}		0.1	1.0	μΑ	$V_{IN} = 0$ to V_{CC}

Electrical Characteristics

continued	continued										
Parameter	Symbol	Minimum	Typical	Maximum	Units	Test Conditions					
Input Low-Voltage	V _{IL1}	-0.6	—	0.8	V	$2.7V \le V_{CC} \le 5.5V$ (Note 2)					
Input High-Voltage	V _{IH1}	2.0	—	V _{CC} + 1	V	2.7V ≤ V _{CC} ≤ 5.5V (Note 2)					
Input Low-Voltage	V _{IL2}	-0.6	—	V _{CC} x 0.3	V	1.8V ≤ V _{CC} ≤ 2.7V (Note 2)					
Input High-Voltage	V _{IH2}	V _{CC} x 0.7		V _{CC} + 1	V	1.8V ≤ V _{CC} ≤ 2.7V (Note 2)					
Output Low-Voltage	V _{OL1}	_	—	0.4	V	$2.7V \le V_{CC} \le 5.5V$, $I_{OL} = 2.1$ mA					
Output High-Voltage	V _{OH1}	2.4	_	—	V	$2.7V \le V_{CC} \le 5.5V$, $I_{OH} = -0.4 \text{ mA}$					
Output Low-Voltage	V _{OL2}	_		0.2	V	$\begin{array}{l} 1.8 \text{V} \leq \text{V}_{\text{CC}} \leq 2.7 \text{V}, \\ \text{I}_{\text{OL}} = 0.15 \text{ mA} \end{array}$					
Output High-Voltage	V _{OH2}	V _{CC} - 0.2	_	—	V	$\begin{array}{l} 1.8 V \leq V_{CC} \leq 2.7 V, \\ I_{OH} = -100 \ \mu A \end{array}$					

Note:

1. Applicable over recommended operating range from: $T_A = -40^{\circ}C$ to $+85^{\circ}C$, $V_{CC} = 1.8V$ to 5.5V (unless otherwise noted).

2. $\ V_{IL}$ min and V_{IH} max are reference only and are not tested.

4.4 AC Characteristics

Table 4-3. AC Characteristics⁽¹⁾

Parameter	Symbol	Minimum	Typical	Maximum	Units	Test Conditions
Clock Frequency, SK	f _{SK}	0	—	2	MHz	$4.5 V \leq V_{CC} \leq 5.5 V$
		0	_	1	MHz	$2.7 V \leq V_{CC} \leq 5.5 V$
		0	—	250	kHz	$1.8 V \le V_{CC} \le 5.5 V$
High Time, SK	t _{sKH}	250	—		ns	$2.7 V \leq V_{CC} \leq 5.5 V$
		1000	—		ns	$1.8 V \le V_{CC} \le 5.5 V$
Low Time, SK	t _{SKL}	250	—		ns	$2.7 V \leq V_{CC} \leq 5.5 V$
		1000	—		ns	$1.8 V \le V_{CC} \le 5.5 V$
Minimum CS Low Time	t _{CS}	250	—		ns	$2.7 V \leq V_{CC} \leq 5.5 V$
		1000	—	—	ns	$1.8 V \le V_{CC} \le 5.5 V$
CS Setup Time	t _{CSS}	50	_	_	ns	$2.7V \le V_{CC} \le 5.5V$, Relative to SK
		200		—	ns	$1.8V \le V_{CC} \le 5.5V$, Relative to SK
DI Setup Time	t _{DIS}	100	_	—	ns	$2.7V \le V_{CC} \le 5.5V$, Relative to SK
		400			ns	$1.8V \le V_{CC} \le 5.5V$, Relative to SK
CS Hold Time	t _{CSH}	0			ns	Relative to SK

Electrical Characteristics

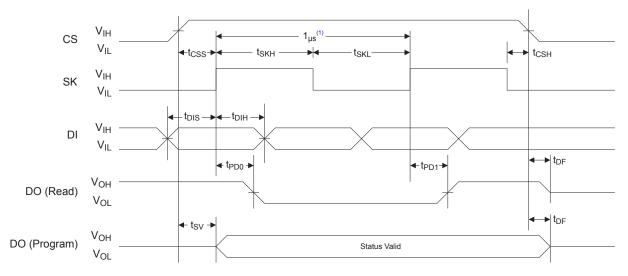
continued									
Parameter	Symbol	Minimum	Typical	Maximum	Units	Test Conditions			
DI Hold Time	t _{DIH}	100		—	ns	$2.7V \le V_{CC} \le 5.5V$, Relative to SK			
		400			ns	$1.8V \le V_{CC} \le 5.5V$, Relative to SK			
Output Delay to 1	t _{PD1}			250	ns	$2.7 V \leq V_{CC} \leq 5.5 V$			
			_	1000	ns	$1.8 V \leq V_{CC} \leq 5.5 V$			
Output Delay to 0	t _{PD0}		_	250	ns	$2.7 V \leq V_{CC} \leq 5.5 V$			
				1000	ns	$1.8 V \leq V_{CC} \leq 5.5 V$			
CS to Status Valid	t _{SV}		_	250	ns	$2.7 V \leq V_{CC} \leq 5.5 V$			
			_	1000	ns	$1.8 V \le V_{CC} \le 5.5 V$			
CS to DO in High-Impedance	t _{DF}			100	ns	$4.5V \le V_{CC} \le 5.5V$, CS = V _{IL}			
				150	ns	$2.7V \le V_{CC} \le 5.5V$, CS = V _{IL} , AT93C46E			
				250	ns	$2.7V \le V_{CC} \le 5.5V$, CS = V _{IL} , AT93C46D			
				400	ns	$\begin{array}{l} 1.8 \text{V} \leq \text{V}_{\text{CC}} \leq 5.5 \text{V}, \\ \text{CS} = \text{V}_{\text{IL}} \end{array}$			
Write Cycle Time	t _{WP}	0.1	3	5	ms	$1.8 V \leq V_{CC} \leq 5.5 V$			

Note:

1. Applicable over recommended operating range from $T_A = -40^{\circ}C$ to +85°C, V_{CC} = as specified, $C_L = 1$ TTL Gate and 100 pF (unless otherwise noted).

4.5 Synchronous Data Timing

Figure 4-1. Synchronous Data Timing



Note:

1. This is the minimum SK period.

4.6 Electrical Specifications

4.6.1 Power-Up Requirements and Reset Behavior

During a power-up sequence, the V_{CC} supplied to the AT93C46D/AT93C46E should monotonically rise from GND to the minimum V_{CC} level, as specified in Table 4-1, with a slew rate no faster than 0.1 V/µs.

4.6.1.1 Device Reset

To prevent inadvertent write operations or any other spurious events from occurring during a power-up sequence, the AT93C46D/AT93C46E includes a Power-on Reset (POR) circuit. Upon power-up, the device will not respond to any commands until the V_{CC} level crosses the internal voltage threshold (V_{POR}) that brings the device out of Reset and into Standby mode.

The system designer must ensure the instructions are not sent to the device until the V_{CC} supply has reached a stable value greater than or equal to the minimum V_{CC} level. Additionally, once the V_{CC} is greater than or equal to the minimum V_{CC} level, the bus master must wait at least t_{PUP} before sending the first command to the device. See Table 4-4 for the values associated with these power-up parameters.

Table 4-4. Power-up Conditions⁽¹⁾

Symbol	Parameter	Min.	Max.	Units
t _{PUP}	Time required after V_{CC} is stable before the device can accept commands	100	_	μs
V _{POR}	Power-on Reset Threshold Voltage	_	1.5	V
t _{POFF}	Minimum time at V_{CC} = 0V between power cycles	500	_	ms

Note:

1. These parameters are characterized but they are not 100% tested in production.

If an event occurs in the system where the V_{CC} level supplied to the AT93C46D/AT93C46E drops below the maximum V_{POR} level specified, it is recommended that a full power cycle sequence be performed by first driving the V_{CC} pin to GND, waiting at least the minimum t_{POFF} time and then performing a new power-up sequence in compliance with the requirements defined in this section.

4.6.2 Pin Capacitance

Table 4-5. Pin Capacitance⁽¹⁾

Symbol	Test Condition	Max.	Units	Conditions
C _{OUT}	Output Capacitance (DO)	5	pF	V _{OUT} = 0V
C _{IN}	Input Capacitance (CS, SK, DI, ORG)	5	pF	V _{IN} = 0V

Note:

1. This parameter is characterized but is not 100% tested in production.

4.6.3 EEPROM Cell Performance Characteristics

Table 4-6. EEPROM Cell Performance Characteristics

Operation	Test Condition	Min.	Max.	Units
Write Endurance ⁽¹⁾	T _A = 25°C, V _{CC} = 5.0V	1,000,000	—	Write Cycles
Data Retention ⁽¹⁾	T _A = 55°C	100		Years

Note:

1. Performance is determined through characterization and the qualification process.

5. Device Commands and Addressing

The AT93C46D/AT93C46E is accessed via a simple and versatile three-wire serial communication interface. Device operation is controlled by seven instructions issued by the Host processor. A valid instruction starts with a rising edge of CS and consists of a Start bit (SB), followed by the appropriate opcode, and the desired memory address location.

Instruction	SB	Opcode	Add	ress	Da	ata	Comments
			X8(<u>1</u>)	X16(<u>1)</u>	X8	X16	
READ	1	10	A ₆ -A ₀	A ₅ -A ₀			Reads data stored in memory at specified address.
EWEN	1	00	11XXXXX	11XXXX			Write Enable must precede all programming modes.
ERASE	1	11	A ₆ -A ₀	A ₅ -A ₀			Erases memory location A_N - A_0 .
WRITE	1	01	A ₆ -A ₀	A ₅ -A ₀	D ₇ -D ₀	D ₁₅ -D ₀	Writes memory location A_N - A_0 .
ERAL	1	00	10XXXXX	10XXXX			Erases all memory locations. Valid only at V_{CC3} . See Table 4-2.
WRAL	1	00	01XXXXX	01XXXX	D ₇ -D ₀	D ₁₅ -D ₀	Writes all memory locations. Valid only at V_{CC3} . See Table 4-2.
EWDS	1	00	00XXXXX	00XXXX			Disables all programming instructions.

Table 5-1. AT93C46D/AT93C46E Instruction Set

Note:

1. The 'x' in the address field represent a "don't care" bit, and must be sent to the device.

Table 5-2. Organization Key for Timing Diagrams

I/O	AT93C46D/AT93C46E (1K)			
	x8(<u>1)</u>	x16		
A _N	A ₆	A ₅		
D _N	D ₇	D ₁₅		

Note:

1. The internal organization of the AT93C46E is x16 only.

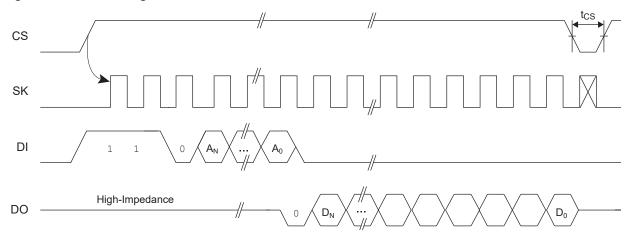
5.1 Read Operation (READ)

The READ instruction contains the address code for the memory location to be read. After the instruction and address are decoded, data from the selected memory location is available at the DO pin. Output data changes are synchronized with the rising edges of the SK pin.

Note: A dummy bit (logic '0') precedes the 8-bit or 16-bit data output string.

Device Commands and Addressing

Figure 5-1. READ Timing



5.2 Erase/Write Enable (EWEN)

To ensure data integrity, the part automatically goes into the Erase/Write Disable (EWDS) state when power is first applied. An Erase/Write Enable (EWEN) instruction must be executed first before any programming instructions can be carried out.

Note: Once in the write enabled state, programming remains enabled until an EWDS instruction is executed, or V_{CC} power is removed from the part.

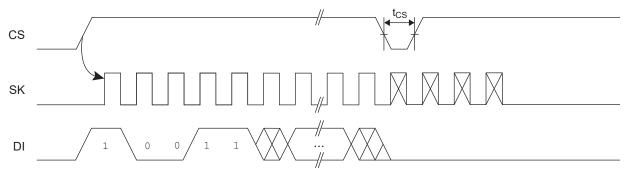


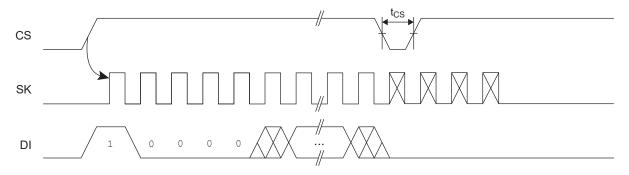
Figure 5-2. EWEN Timing

5.3 Erase/Write Disable (EWDS)

To protect against accidental data disturbance, the Erase/Write Disable (EWDS) instruction disables all programming modes and should be executed after all programming operations. The operation of the READ instruction is independent of both the EWEN and EWDS instructions and can be executed at any time.

Device Commands and Addressing

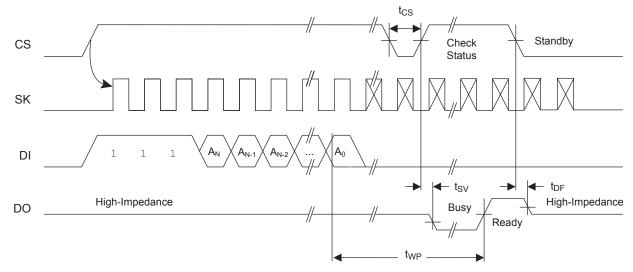
Figure 5-3. EWDS Timing



5.4 Erase Operation (ERASE)

The ERASE instruction programs all bits in the specified memory location to the logic '1' state. The self-timed erase cycle starts once the ERASE instruction and address are decoded. The DO pin outputs the Ready/Busy status of the part if CS is brought high after being kept low for a minimum of t_{CS} . A logic '1' at the DO pin indicates that the selected memory location has been erased, and the part is ready for another instruction.



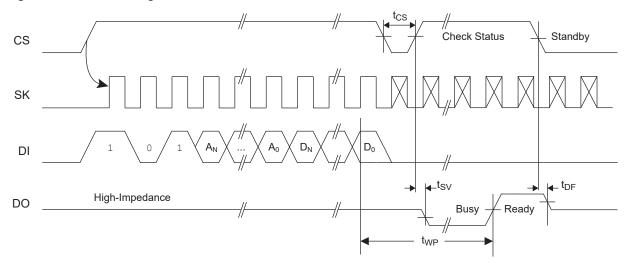


5.5 Write Operation (WRITE)

The WRITE instruction contains the 8 bits or 16 bits of data to be written into the specified memory location. The self-timed programming cycle, t_{WP} , starts after the last bit of data is received at DI pin. The DO pin outputs the Ready/ Busy status of the part if CS is brought high after being kept low for a minimum of t_{CS} . A logic '0' at DO indicates that programming is still in progress. A logic '1' indicates that the memory location at the specified address has been written with the data pattern contained in the instruction, and the part is ready for further instructions. A Ready/Busy status cannot be obtained if CS is brought high after the end of the self-timed programming cycle, t_{WP} .

Device Commands and Addressing

Figure 5-5. WRITE Timing



5.6 Write All (WRAL)

The Write All (WRAL) instruction programs all memory locations with the data patterns specified in the instruction. The DO pin outputs the Ready/Busy status of the part if CS is brought high after being kept low for a minimum of t_{CS} .

Note: The WRAL instruction is valid only at V_{CC3} (see Table 4-2).

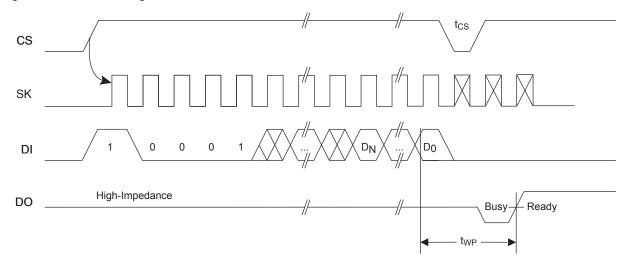


Figure 5-6. WRAL Timing

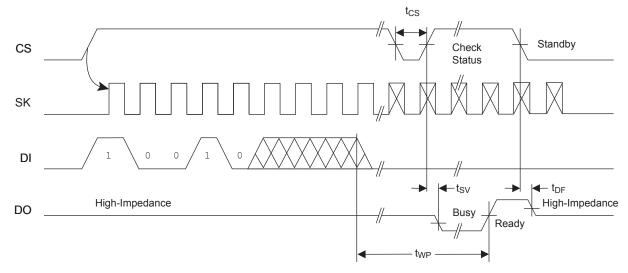
5.7 Erase All (ERAL)

The Erase All (ERAL) instruction programs every bit in the memory array to the logic '1' state and is primarily used for testing purposes. The DO pin outputs the Ready/Busy status of the part if CS is brought high after being kept low for a minimum of t_{CS} .

Note: The ERAL instruction is valid only at V_{CC3} (see Table 4-2).

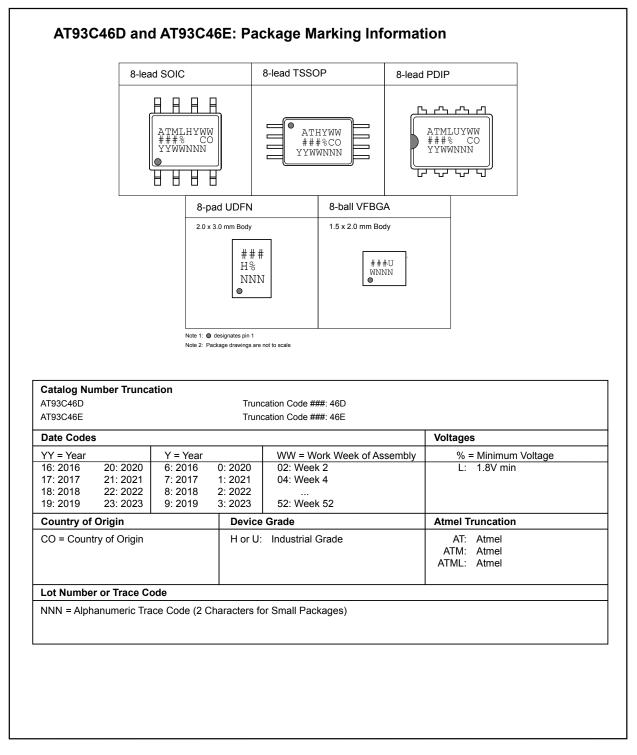
Device Commands and Addressing





6. Packaging Information

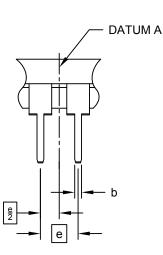
6.1 Package Marking Information

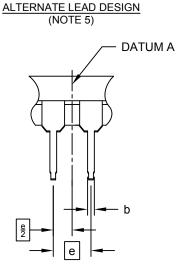


Packaging Information

8-Lead Plastic Dual In-Line (P) - 300 mil Body [PDIP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging





	Units		INCHES	
Dimension	Limits	MIN	NOM	MAX
Number of Pins	N		8	
Pitch	е		.100 BSC	
Top to Seating Plane	Α	-	-	.210
Molded Package Thickness	A2	.115	.130	.195
Base to Seating Plane	A1	.015	-	-
Shoulder to Shoulder Width	E	.290	.310	.325
Molded Package Width	E1	.240	.250	.280
Overall Length	D	.348	.365	.400
Tip to Seating Plane	L	.115	.130	.150
Lead Thickness	С	.008	.010	.015
Upper Lead Width	b1	.040	.060	.070
Lower Lead Width	b	.014	.018	.022
Overall Row Spacing §	eB	-	-	.430

Notes:

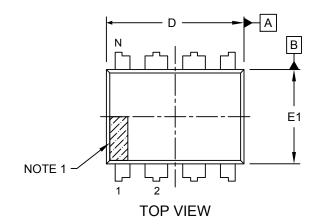
- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. § Significant Characteristic
- 3. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" per side.
- Dimensioning and tolerancing per ASME Y14.5M BSC: Basic Dimension. Theoretically exact value shown without tolerances.
- 5. Lead design above seating plane may vary, based on assembly vendor.

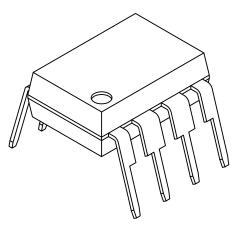
Microchip Technology Drawing No. C04-018-P Rev E Sheet 2 of 2

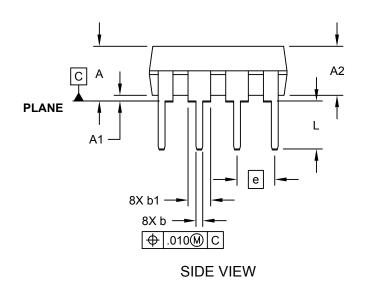
Packaging Information

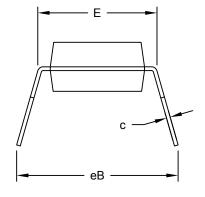
8-Lead Plastic Dual In-Line (P) - 300 mil Body [PDIP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging







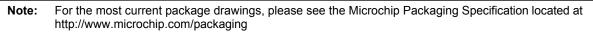


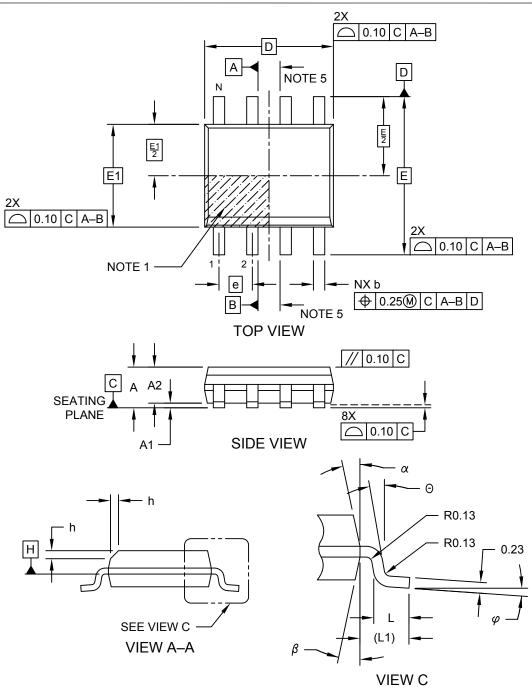
END VIEW

Microchip Technology Drawing No. C04-018-P Rev E Sheet 1 of 2

Packaging Information

8-Lead Plastic Small Outline (SN) - Narrow, 3.90 mm (.150 In.) Body [SOIC]



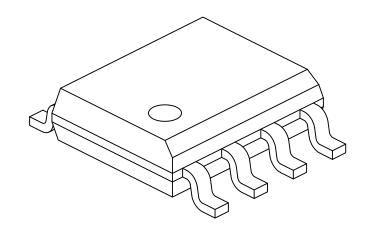


Microchip Technology Drawing No. C04-057-SN Rev F Sheet 1 of 2

Packaging Information

8-Lead Plastic Small Outline (SN) - Narrow, 3.90 mm (.150 In.) Body [SOIC]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units			MILLIMETERS			
Dimensio	on Limits	MIN	NOM	MAX			
Number of Pins	N		8				
Pitch	Pitch e		1.27 BSC				
Overall Height	Α	-	-	1.75			
Molded Package Thickness	A2	1.25	-	-			
Standoff §	A1	0.10	-	0.25			
Overall Width	E	6.00 BSC					
Molded Package Width	E1	3.90 BSC					
Overall Length	D	4.90 BSC					
Chamfer (Optional)	h	0.25	-	0.50			
Foot Length	L	0.40	-	1.27			
Footprint	L1		1.04 REF				
Foot Angle	φ	0°	-	8°			
Lead Thickness	С	0.17	-	0.25			
Lead Width	b	0.31	-	0.51			
Mold Draft Angle Top	α	5°	-	15°			
Mold Draft Angle Bottom	β	5°	-	15°			

Notes:

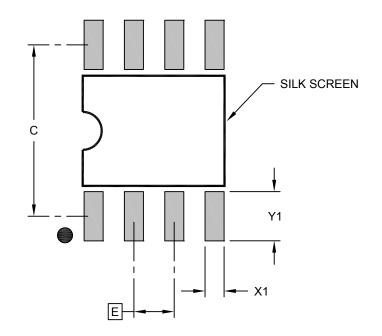
- 1. Pin 1 visual index feature may vary, but must be located within the hatched area.
- 2. § Significant Characteristic
- 3. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15mm per side.
- 4. Dimensioning and tolerancing per ASME Y14.5M
 - BSC: Basic Dimension. Theoretically exact value shown without tolerances.
 - REF: Reference Dimension, usually without tolerance, for information purposes only.
- 5. Datums A & B to be determined at Datum H.

Microchip Technology Drawing No. C04-057-SN Rev F Sheet 2 of 2

Packaging Information

8-Lead Plastic Small Outline (SN) - Narrow, 3.90 mm (.150 In.) Body [SOIC]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	Units	MILLIMETERS		
Dimension	Limits	MIN	NOM	MAX
Contact Pitch	E		1.27 BSC	
Contact Pad Spacing	С		5.40	
Contact Pad Width (X8)	X1			0.60
Contact Pad Length (X8)	Y1			1.55

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

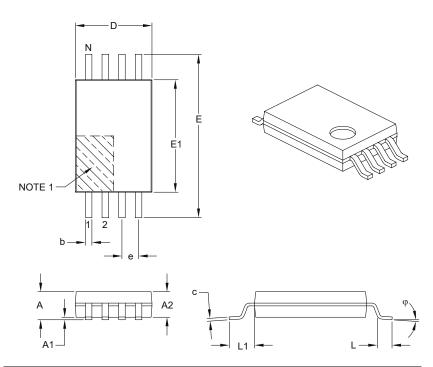
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-2057-SN Rev F

Packaging Information

8-Lead Plastic Thin Shrink Small Outline (ST) – 4.4 mm Body [TSSOP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units		MILLIMETERS	6
Din	nension Limits	MIN	NOM	MAX
Number of Pins	N		8	
Pitch	е		0.65 BSC	
Overall Height	А	-	-	1.20
Molded Package Thickness	A2	0.80	1.00	1.05
Standoff	A1	0.05	-	0.15
Overall Width	E		6.40 BSC	
Molded Package Width	E1	4.30	4.40	4.50
Molded Package Length	D	2.90	3.00	3.10
Foot Length	L	0.45	0.60	0.75
Footprint	L1		1.00 REF	
Foot Angle	φ	0°	-	8°
Lead Thickness	С	0.09	-	0.20
Lead Width	b	0.19	-	0.30

Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.

2. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15 mm per side.

3. Dimensioning and tolerancing per ASME Y14.5M.

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

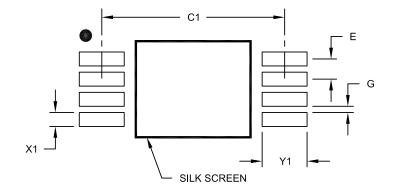
REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-086B

Packaging Information

8-Lead Plastic Thin Shrink Small Outline (ST) - 4.4 mm Body [TSSOP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	Units	Ν	ILLIMETER	S
Dimension	Limits	MIN	NOM	MAX
Contact Pitch	E		0.65 BSC	
Contact Pad Spacing	C1		5.90	
Contact Pad Width (X8)	X1			0.45
Contact Pad Length (X8)	Y1			1.45
Distance Between Pads	G	0.20		

Notes:

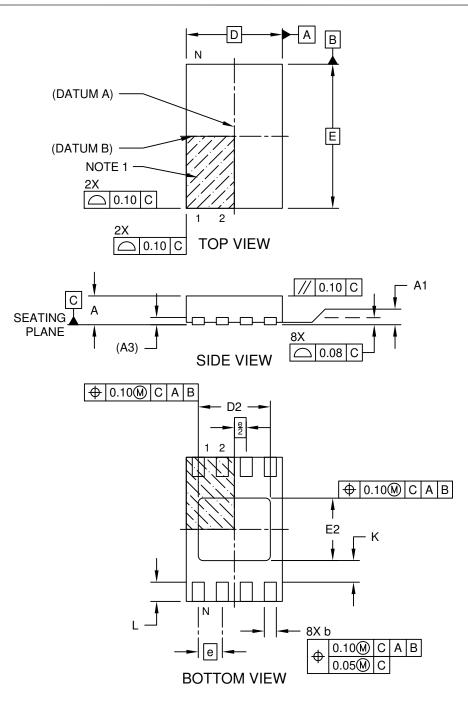
1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2086A

8-Lead Ultra Thin Plastic Dual Flat, No Lead Package (Q4B) - 2x3 mm Body [UDFN] Atmel Legacy YNZ Package

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging

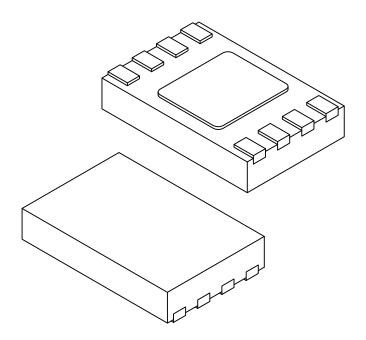


Microchip Technology Drawing C04-21355-Q4B Rev A Sheet 1 of 2

Packaging Information

8-Lead Ultra Thin Plastic Dual Flat, No Lead Package (Q4B) - 2x3 mm Body [UDFN] Atmel Legacy YNZ Package

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units	Ν	MILLIMETERS			
Dimension	Limits	MIN	NOM	MAX		
Number of Terminals	Ν		8			
Pitch	е		0.50 BSC			
Overall Height	Α	0.50	0.55	0.60		
Standoff	A1	0.00	0.02	0.05		
Terminal Thickness	A3		0.152 REF			
Overall Length	D	2.00 BSC				
Exposed Pad Length	D2	1.40	1.50	1.60		
Overall Width	E		3.00 BSC			
Exposed Pad Width	E2	1.20	1.30	1.40		
Terminal Width	b	0.18	0.25	0.30		
Terminal Length	L	0.35	0.40	0.45		
Terminal-to-Exposed-Pad	K	0.20	-	-		

Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.

2. Package is saw singulated

3. Dimensioning and tolerancing per ASME Y14.5M

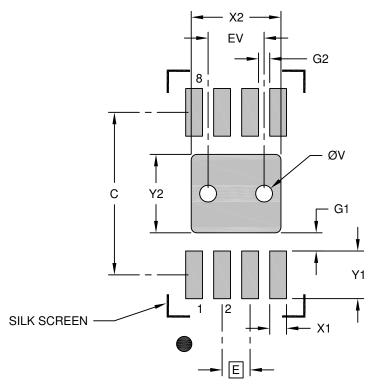
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing C04-21355-Q4B Rev A Sheet 2 of 2

8-Lead Ultra Thin Plastic Dual Flat, No Lead Package (Q4B) - 2x3 mm Body [UDFN] Atmel Legacy YNZ Package

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



RECOMMENDED LAND PATTERN

	Units		IILLIMETER	S
Dimension	Limits	MIN	NOM	MAX
Contact Pitch	E		0.50 BSC	
Optional Center Pad Width	X2			1.60
Optional Center Pad Length	Y2			1.40
Contact Pad Spacing	С		2.90	
Contact Pad Width (X8)	X1			0.30
Contact Pad Length (X8)	Y1			0.85
Contact Pad to Center Pad (X8)	G1	0.20		
Contact Pad to Contact Pad (X6)	G2	0.33		
Thermal Via Diameter	V		0.30	
Thermal Via Pitch	EV		1.00	

Notes:

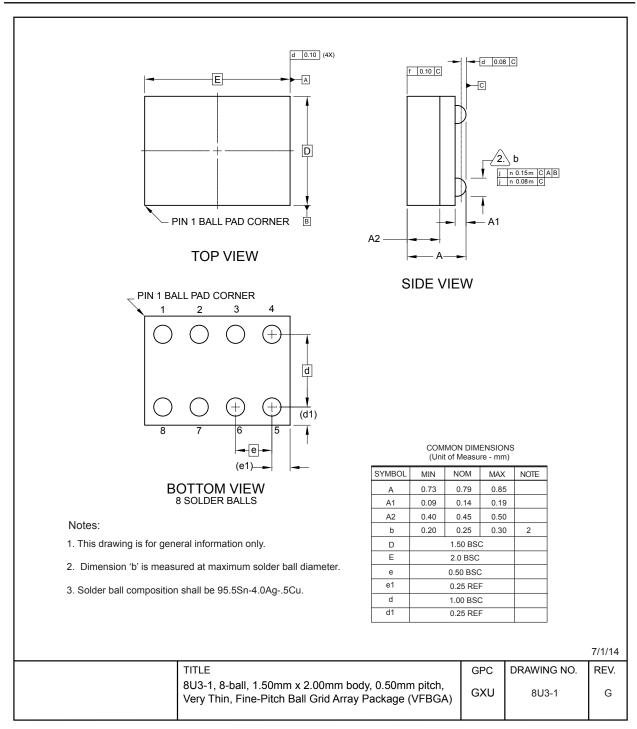
1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

2. For best soldering results, thermal vias, if used, should be filled or tented to avoid solder loss during reflow process

Microchip Technology Drawing C04-21355-Q4B Rev A

AT93C46D/AT93C46E Packaging Information



Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging.

7. Revision History

Revision B (February 2020)

Updated section content throughout for clarification. Updated test conditions values. Updated SOIC (SN) package drawing.

Revision A (July 2019)

Updated to the Microchip template. Microchip DS20006224 replaces Atmel documents 5193 and 5207. Updated Package Marking Information. Removed lead finish designation. Updated trace code format in package markings. Updated section content throughout for clarification. Updated the 8U3-1 VFBGA package drawing. Updated the PDIP, SOIC, TSSOP and UDFN package drawings to Microchip format.

Atmel AT93C46E 5207 Revision F (January 2015)

Updated ordering information section.

Atmel AT93C46D 5193 Revision H (January 2015)

Added the UDFN expanded quantity option and the ordering information section. Updated the 8MA2 and 8P3 package drawings.

Atmel AT93C46E 5207 Revision E (October 2014)

Added the part markings and ordering code detail. Updated the package outline drawings and the 8A2 to 8X. Updated the template, Atmel logos, and the disclaimer page.

Atmel AT93C46D 5193 Revision G (August 2014)

Updated package drawings, template, logos, and disclaimer page.

Atmel AT93C46E 5207 Revision D (January 2008)

Removed the 'preliminary' status.

Atmel AT93C46D 5193 Revision F (January 2008)

Removed the 'preliminary' status.

Atmel AT93C46E 5207 Revision C (November 2007)

Modified the 'max' value in AC Characteristics table.

Atmel AT93C46D 5193 Revision E (November 2007)

Modified the 'max' value in AC Characteristics table.

Atmel AT93C46E 5207 Revision B (August 2007)

Modified Part Marking Schemes.

Atmel AT93C46D 5193 Revision D (August 2007)

Moved Pinout figure. Added new feature for Die Sales. Modified Ordering Information table layout. Modified Park Marking Schemes.

Atmel AT93C46D 5193 Revision C (June 2007)

Updated to new template. Added Product Markup Scheme. Added Technical email contact. Corrected Figures 4 and 5.

Atmel AT93C46D 5193 Revision B (February 2007)

Added 'Ultra Thin' description to 8-lead Mini-MAP package.

Revision History

Atmel AT93C46E 5207 Revision A (January 2007) Initial document release.

Atmel AT93C46D 5193 Revision A (January 2007) Initial document release.

The Microchip Website

Microchip provides online support via our website at http://www.microchip.com/. This website is used to make files and information easily available to customers. Some of the content available includes:

- **Product Support** Data sheets and errata, application notes and sample programs, design resources, user's guides and hardware support documents, latest software releases and archived software
- General Technical Support Frequently Asked Questions (FAQs), technical support requests, online discussion groups, Microchip design partner program member listing
- **Business of Microchip** Product selector and ordering guides, latest Microchip press releases, listing of seminars and events, listings of Microchip sales offices, distributors and factory representatives

Product Change Notification Service

Microchip's product change notification service helps keep customers current on Microchip products. Subscribers will receive email notification whenever there are changes, updates, revisions or errata related to a specified product family or development tool of interest.

To register, go to http://www.microchip.com/pcn and follow the registration instructions.

Customer Support

Users of Microchip products can receive assistance through several channels:

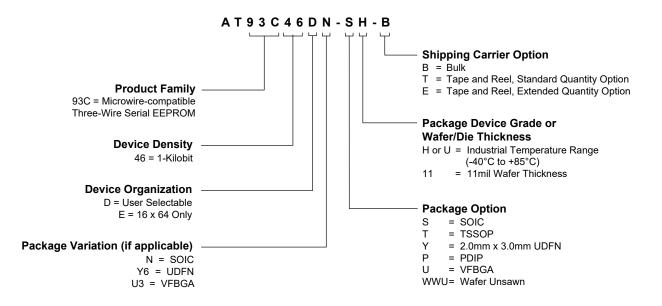
- Distributor or Representative
- Local Sales Office
- Embedded Solutions Engineer (ESE)
- Technical Support

Customers should contact their distributor, representative or ESE for support. Local sales offices are also available to help customers. A listing of sales offices and locations is included in this document.

Technical support is available through the website at: http://www.microchip.com/support

Product Identification System

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.



Note: Refer to the automotive data sheet for automotive grade ordering information.

Device	Package	Package Drawing Code	Package Option	Organization	Shipping Carrier Option	Device Grade
AT93C46DN-SH-B	SOIC	SN	S	User Selectable	Bulk (Tubes)	
AT93C46EN-SH-T	SOIC	SN	S	16 X 64	Tape and Reel	
AT93C46E-TH-B	TSSOP	ST	Т	16 X 64	Bulk (Tubes)	
AT93C46D-TH-T	TSSOP	ST	Т	User Selectable	Tape and Reel	Industrial
AT93C46DY6-YH-T	UDFN	Q4B	Y	User Selectable	Tape and Reel	Temperature (-40°C to 85°C)
AT93C46DY6-YH-E	UDFN	Q4B	Y	User Selectable	Extended Qty., Tape and Reel	10 00 07
AT93C46E-PU	PDIP	Р	Р	16 X 64	Bulk (Tubes)	
AT93C46DU3-UU-T	VFBGA	8U3-1	U	User Selectable	Tape and Reel	

Microchip Devices Code Protection Feature

Note the following details of the code protection feature on Microchip devices:

- · Microchip products meet the specification contained in their particular Microchip Data Sheet.
- Microchip believes that its family of products is one of the most secure families of its kind on the market today, when used in the intended manner and under normal conditions.
- There are dishonest and possibly illegal methods used to breach the code protection feature. All of these methods, to our knowledge, require using the Microchip products in a manner outside the operating

specifications contained in Microchip's Data Sheets. Most likely, the person doing so is engaged in theft of intellectual property.

- · Microchip is willing to work with the customer who is concerned about the integrity of their code.
- Neither Microchip nor any other semiconductor manufacturer can guarantee the security of their code. Code protection does not mean that we are guaranteeing the product as "unbreakable."

Code protection is constantly evolving. We at Microchip are committed to continuously improving the code protection features of our products. Attempts to break Microchip's code protection feature may be a violation of the Digital Millennium Copyright Act. If such acts allow unauthorized access to your software or other copyrighted work, you may have a right to sue for relief under that Act.

Legal Notice

Information contained in this publication regarding device applications and the like is provided only for your convenience and may be superseded by updates. It is your responsibility to ensure that your application meets with your specifications. MICROCHIP MAKES NO REPRESENTATIONS OR WARRANTIES OF ANY KIND WHETHER EXPRESS OR IMPLIED, WRITTEN OR ORAL, STATUTORY OR OTHERWISE, RELATED TO THE INFORMATION, INCLUDING BUT NOT LIMITED TO ITS CONDITION, QUALITY, PERFORMANCE, MERCHANTABILITY OR FITNESS FOR PURPOSE. Microchip disclaims all liability arising from this information and its use. Use of Microchip devices in life support and/or safety applications is entirely at the buyer's risk, and the buyer agrees to defend, indemnify and hold harmless Microchip from any and all damages, claims, suits, or expenses resulting from such use. No licenses are conveyed, implicitly or otherwise, under any Microchip intellectual property rights unless otherwise stated.

Trademarks

The Microchip name and logo, the Microchip logo, Adaptec, AnyRate, AVR, AVR logo, AVR Freaks, BesTime, BitCloud, chipKIT, chipKIT logo, CryptoMemory, CryptoRF, dsPIC, FlashFlex, flexPWR, HELDO, IGLOO, JukeBlox, KeeLoq, Kleer, LANCheck, LinkMD, maXStylus, maXTouch, MediaLB, megaAVR, Microsemi, Microsemi logo, MOST, MOST logo, MPLAB, OptoLyzer, PackeTime, PIC, picoPower, PICSTART, PIC32 logo, PolarFire, Prochip Designer, QTouch, SAM-BA, SenGenuity, SpyNIC, SST, SST Logo, SuperFlash, Symmetricom, SyncServer, Tachyon, TempTrackr, TimeSource, tinyAVR, UNI/O, Vectron, and XMEGA are registered trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

APT, ClockWorks, The Embedded Control Solutions Company, EtherSynch, FlashTec, Hyper Speed Control, HyperLight Load, IntelliMOS, Libero, motorBench, mTouch, Powermite 3, Precision Edge, ProASIC, ProASIC Plus, ProASIC Plus logo, Quiet-Wire, SmartFusion, SyncWorld, Temux, TimeCesium, TimeHub, TimePictra, TimeProvider, Vite, WinPath, and ZL are registered trademarks of Microchip Technology Incorporated in the U.S.A.

Adjacent Key Suppression, AKS, Analog-for-the-Digital Age, Any Capacitor, AnyIn, AnyOut, BlueSky, BodyCom, CodeGuard, CryptoAuthentication, CryptoAutomotive, CryptoCompanion, CryptoController, dsPICDEM, dsPICDEM.net, Dynamic Average Matching, DAM, ECAN, EtherGREEN, In-Circuit Serial Programming, ICSP, INICnet, Inter-Chip Connectivity, JitterBlocker, KleerNet, KleerNet Iogo, memBrain, Mindi, MiWi, MPASM, MPF, MPLAB Certified Iogo, MPLIB, MPLINK, MultiTRAK, NetDetach, Omniscient Code Generation, PICDEM, PICDEM.net, PICkit, PICtail, PowerSmart, PureSilicon, QMatrix, REAL ICE, Ripple Blocker, SAM-ICE, Serial Quad I/O, SMART-I.S., SQI, SuperSwitcher, SuperSwitcher II, Total Endurance, TSHARC, USBCheck, VariSense, ViewSpan, WiperLock, Wireless DNA, and ZENA are trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

SQTP is a service mark of Microchip Technology Incorporated in the U.S.A.

The Adaptec logo, Frequency on Demand, Silicon Storage Technology, and Symmcom are registered trademarks of Microchip Technology Inc. in other countries.

GestIC is a registered trademark of Microchip Technology Germany II GmbH & Co. KG, a subsidiary of Microchip Technology Inc., in other countries.

All other trademarks mentioned herein are property of their respective companies.

© 2020, Microchip Technology Incorporated, Printed in the U.S.A., All Rights Reserved.

ISBN: 978-1-5224-5601-8

AMBA, Arm, Arm7, Arm7TDMI, Arm9, Arm11, Artisan, big.LITTLE, Cordio, CoreLink, CoreSight, Cortex, DesignStart, DynamIQ, Jazelle, Keil, Mali, Mbed, Mbed Enabled, NEON, POP, RealView, SecurCore, Socrates, Thumb, TrustZone, ULINK, ULINK2, ULINK-ME, ULINK-PLUS, ULINKpro, μVision, Versatile are trademarks or registered trademarks of Arm Limited (or its subsidiaries) in the US and/or elsewhere.

Quality Management System

For information regarding Microchip's Quality Management Systems, please visit http://www.microchip.com/quality.



Worldwide Sales and Service

MERICAS	ASIA/PACIFIC	ASIA/PACIFIC	EUROPE
Corporate Office	Australia - Sydney	India - Bangalore	Austria - Wels
355 West Chandler Blvd.	Tel: 61-2-9868-6733	Tel: 91-80-3090-4444	Tel: 43-7242-2244-39
handler, AZ 85224-6199	China - Beijing	India - New Delhi	Fax: 43-7242-2244-393
el: 480-792-7200	Tel: 86-10-8569-7000	Tel: 91-11-4160-8631	Denmark - Copenhagen
ax: 480-792-7277	China - Chengdu	India - Pune	Tel: 45-4450-2828
echnical Support:	Tel: 86-28-8665-5511	Tel: 91-20-4121-0141	Fax: 45-4485-2829
ttp://www.microchip.com/support	China - Chongging	Japan - Osaka	Finland - Espoo
Veb Address:	Tel: 86-23-8980-9588	Tel: 81-6-6152-7160	Tel: 358-9-4520-820
ttp://www.microchip.com	China - Dongguan	Japan - Tokyo	France - Paris
tlanta	Tel: 86-769-8702-9880	Tel: 81-3-6880- 3770	Tel: 33-1-69-53-63-20
uluth, GA	China - Guangzhou	Korea - Daegu	Fax: 33-1-69-30-90-79
el: 678-957-9614	Tel: 86-20-8755-8029	Tel: 82-53-744-4301	Germany - Garching
ax: 678-957-1455	China - Hangzhou	Korea - Seoul	Tel: 49-8931-9700
ustin, TX	Tel: 86-571-8792-8115	Tel: 82-2-554-7200	Germany - Haan
el: 512-257-3370	China - Hong Kong SAR	Malaysia - Kuala Lumpur	Tel: 49-2129-3766400
oston	Tel: 852-2943-5100	Tel: 60-3-7651-7906	Germany - Heilbronn
/estborough, MA	China - Nanjing	Malaysia - Penang	Tel: 49-7131-72400
el: 774-760-0087	Tel: 86-25-8473-2460	Tel: 60-4-227-8870	Germany - Karlsruhe
ax: 774-760-0088	China - Qingdao	Philippines - Manila	Tel: 49-721-625370
hicago	Tel: 86-532-8502-7355	Tel: 63-2-634-9065	Germany - Munich
asca, IL	China - Shanghai	Singapore	Tel: 49-89-627-144-0
el: 630-285-0071	Tel: 86-21-3326-8000	Tel: 65-6334-8870	Fax: 49-89-627-144-44
ax: 630-285-0075	China - Shenyang	Taiwan - Hsin Chu	Germany - Rosenheim
allas	Tel: 86-24-2334-2829	Tel: 886-3-577-8366	Tel: 49-8031-354-560
ddison, TX	China - Shenzhen	Taiwan - Kaohsiung	Israel - Ra'anana
el: 972-818-7423	Tel: 86-755-8864-2200	Tel: 886-7-213-7830	Tel: 972-9-744-7705
ax: 972-818-2924	China - Suzhou	Taiwan - Taipei	Italy - Milan
etroit	Tel: 86-186-6233-1526	Tel: 886-2-2508-8600	Tel: 39-0331-742611
ovi, MI	China - Wuhan	Thailand - Bangkok	Fax: 39-0331-466781
el: 248-848-4000	Tel: 86-27-5980-5300	Tel: 66-2-694-1351	Italy - Padova
ouston, TX	China - Xian	Vietnam - Ho Chi Minh	Tel: 39-049-7625286
el: 281-894-5983	Tel: 86-29-8833-7252	Tel: 84-28-5448-2100	Netherlands - Drunen
dianapolis	China - Xiamen		Tel: 31-416-690399
oblesville, IN	Tel: 86-592-2388138		Fax: 31-416-690340
el: 317-773-8323	China - Zhuhai		Norway - Trondheim
ax: 317-773-5453	Tel: 86-756-3210040		Tel: 47-72884388
el: 317-536-2380			Poland - Warsaw
os Angeles			Tel: 48-22-3325737
lission Viejo, CA			Romania - Bucharest
el: 949-462-9523			Tel: 40-21-407-87-50
ax: 949-462-9608			Spain - Madrid
el: 951-273-7800			Tel: 34-91-708-08-90
aleigh, NC			Fax: 34-91-708-08-91
el: 919-844-7510			Sweden - Gothenberg
ew York, NY			Tel: 46-31-704-60-40
el: 631-435-6000			Sweden - Stockholm
an Jose, CA			Tel: 46-8-5090-4654
el: 408-735-9110			UK - Wokingham
el: 408-436-4270			Tel: 44-118-921-5800
anada - Toronto			Fax: 44-118-921-5820
el: 905-695-1980			1 ax. ++-110-32 1-3020
ax: 905-695-2078			